

Precision Low-voltage Amplifier; DC to 2 kHz

Features

Low Offset: 10 µV Max Low Drift: 0.05 µV/°C Max Low Noise $-6 \frac{\text{mV}}{\text{Hz}}$ @ 0.5 Hz -0.1 to 10 Hz = 125 nVp-p – 1/f corner @ 0.08 Hz Open-loop Voltage Gain – 300 dB Typical – 200 dB Minimum □Rail-to-rail Output Swing Slew Rate: 5 V/µs

Applications

Thermocouple/Thermopile Amplifiers Load Cell and Bridge Transducer Amplifiers Precision Instrumentation □Battery-powered Systems

Description

The CS3001 single amplifier and the CS3002 dual amplifier are designed for precision amplification of lowlevel signals and are ideally suited to applications that require very high closed-loop gains. These amplifiers achieve excellent offset stability, super-high open-loop gain, and low noise over time and temperature. The devices also exhibit excellent CMRR and PSRR. The common mode input range includes the negative supply rail. The amplifiers operate with any total supply voltage from 2.7 V to 6.7 V (±1.35 V to ±3.35 V).

Pin Configurations

Thermopile Amplifier with a Gain of 650 V/V

CS3001 CS3002

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ELECTRICAL CHARACTERISTICS $V_+ = +5$ V, $V_+ = 0$ V, VCM = 2.5 V ([Note 1](#page-2-3))

Notes: 1. Symbol "•" denotes specification applies over -40 to +85 °C.

- 2. This parameter is guaranteed by design and laboratory characterization. Thermocouple effects prohibit accurate measurement of these parameters in automatic test systems.
- 3. 1000-hour life test data @ 125 °C indicates randomly distributed variation approximately equal to measurement repeatability of 1 μ V.
- 4. Measured within the specified common mode range limits.
- 5. Guaranteed within the output limits of (V+ -0.3 V) to (V- +0.3 V). Tested with proprietary production test method.
- 6. PWDN input has an internal pullup resistor to V+ of approximately 800 kΩ and is the major source of current consumption when PWDN is active low.
- 7. The device has a controlled start-up behavior due to its complex open loop gain characteristics. Startup time applies when supply voltage is applied or when PDWN is released.

ABSOLUTE MAXIMUM RATINGS

2. TYPICAL PERFORMANCE PLOTS

Figure 1. Noise vs. Frequency (Measured)

Figure 3. 0.01 Hz to 10 Hz Noise

Figure 5. Supply Current vs. Temperature, 3001

Figure 2. Noise vs. Frequency

Figure 4. Offset Voltage Stability (DC to 3.2 Hz)

Figure 6. Supply Current vs. Temperature, 3002

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Typical Performance Plots (Cont.)

Figure 7. Supply Current vs. Voltage, 3001

Figure 8. Supply Current vs. Voltage, 3002

Figure 9. Open-loop Gain and Phase vs. Frequency

Typical Performance Plots (Cont.)

Figure 10. Open-loop Gain and Phase vs. Frequency (Expanded)

Figure 11. Input Bias Current vs. Supply Voltage

Typical Performance Plots (Cont.)

Figure 12. Input Bias Current vs. Common Mode Voltage

Figure 14. Voltage Swing vs. Output Current (5 V)

3. CS3001/CS3002 OVERVIEW

The CS3001/CS3002 amplifiers are designed for precision measurement of signals from DC to 2 kHz when operating from a supply voltage of +2.7 V to $+6.7$ V (\pm 1.35 to \pm 3.35 V). The amplifiers are designed with a patented architecture that utilizes multiple amplifier stages to yield very high open loop gain at frequencies of 10 kHz and below. The amplifiers yield low noise and low offset drift while consuming relatively low supply current. An increase in noise floor above 2 kHz is the result of intermediate stages of the amplifier being operated at very low currents. The amplifiers are intended for amplifying small signals with large gains in applications where the output of the amplifier can be band-limited to frequencies below 2 kHz.

3.1 Open-loop Gain and Phase Response

[Figure 15](#page-7-2) illustrates the open loop gain and phase response of the CS3001/CS3002. The gain slope of the amplifier is about –100 dB/decade between 500 Hz and 60 kHz and transitions to –20 dB/decade between 60 kHz and its unity gain crossover frequency at about 4.8 MHz. Phase margin at unity gain is about 70 degrees; gain margin is about 20 dB.

Figure 15. CS3001/CS3002 Open-loop Gain and Phase Response

3.2 Open-loop Gain and Stability Compensation

3.2.1 Discussion

The CS3001 and CS3002 achieve ultra-high open loop gain. [Figure 16](#page-8-2) illustrates the amplifier in a non-inverting gain configuration. The open loop gain and phase plots indicate that the amplifier is stable for closed-loop gains less than 50 V/V and $R1 \le 100$ Ohms. For a gain of 50, the phase margin is between 40° and 60° depending upon the loading conditions. As shown in [Figure 17, on page 12,](#page-9-0) the operational amplifier has an input capacitance at the $+$ and $-$ signal inputs of typically 50 pF. This

capacitance adds an additional pole in the loop gain transfer function at a frequency of $f = 1/(2\pi R^*C_{in})$ where R is the parallel combination of R1 and R2 (R1 || R2). A higher value for R produces a pole at a lower frequency, thus reducing the phase margin. R1 is recommended to be less than or equal to 100 ohms, which results in a pole at 30 MHz or higher. If a higher value of R1 is desired, a compensation capacitor (C2) should be added in parallel with R2. C2 should be chosen such that $R2*C2 \ge R1*C_{in}$.

Figure 16. Non-inverting Gain Configuration

Figure 17. Non-inverting Gain Configuration with Compensation

The feedback capacitor C2 is required for closedloop gains greater than 50 V/V. The capacitor introduces a pole and a zero in the loop gain transfer function,

$$
T = \frac{-\left(1 + \frac{s}{z_1}\right)}{\left(1 + \frac{s}{p_1}\right)} A_{ol}
$$

$$
P_1 = \frac{1}{2\pi (R_1 \| R_2) C_2} \approx \frac{1}{2\pi (R_1 C_2)} \quad \text{for} \quad R_2 \gg R_1
$$

$$
Z_1 = \frac{1}{2\pi (A \times R_1) C_2} \quad \text{where} \quad |A| = \frac{R_2}{R_1}
$$

$$
Z_1 = \frac{1}{2\pi (R_2) C_2}
$$

This indicates that the separation of the pole and the zero is governed by the closed loop gain. It is required that the zero falls on the steep slope (–100 dB/decade) of the loop gain plot so that there

is some gain higher than 0 dB (typically 20 dB) at the hand-over frequency (the frequency at which the slope changes from – 100 dB/decade to –20 dB/decade).

The loop gain plot shown in [Figure 18](#page-10-0) illustrates the unity gain configuration, and indicates how this is modified when using the amplifier in a higher gain configuration with compensation. If it is configured for higher gain, for example, 60 dB, the x–axis will move up by 60 dB (line B). Capacitor C2 adds a zero and a pole. The modified plot indicates the effects of introducing the pole and zero due to capacitor C2. The pole can be located at any frequency higher than the hand-over frequency, the zero has to be at a frequency lower than the handover frequency so as to provide adequate gain mar-

gin. The separation between the pole and the zero is governed by the closed loop gain. The zero (z_1) occurs at the intersection of the –100 dB/decade and –80 dB/decade slopes. The point X in the figure should be at closed loop gain plus 20 dB gain margin. The value for $C2 = 1/(2\pi R1 \text{ P}1)$. Setting the pole of the filter to $P1 = 1$ MHz works very well and is independent of gain. As the closed loop gain is changed, the zero location is also modified if R1 remains fixed. Capacitor C2 can be increased in value to limit the amplifier's rising noise above 2 kHz.

Figure 18. Loop Gain Plot: Unity Gain and with Pole-zero Compensation

3.2.2 Gain Calculations Summary and Recommendations

Condition #1: |Av| ≤ **50 and R1** ≤ **100** Ω

The Opamp is inherently stable for $|Av| \le 50$ and $R1 \le 100 \Omega$. No C2 compensation capacitor across R2 is required.

- $|Av| = 1$ configuration has 70° phase margin and 20 dB gain margin.
- $|Av| = 50$ configuration has phase margin between 40° for $C_{\text{LOAD}} \le 100 \text{ pF}$ and 60° for $C_{\text{LOAD}} = 0$ pF.

Condition #2: |Av| ≤ **50 and R1** > **100** Ω

Compensation capacitor C2 across R2 is required. Calculate C2 using the following formula:

 $C2 \geq (R1 \cdot C_{in}) / R2$, where Cin = 50 pF

Condition #3: |Av| > **50**

Compensation capacitor C2 across R2 is required. Calculate and verify a value for C2 using the following steps.

Calculate the Compensation Capacitor Value:

1) Calculate a value for C2 using the following formula:

 $C2 = 1 / [2\pi (R1||R2) \cdot P1]$, where P1 = 1 MHz

To simplify the calculation, set the pole of the filter to $P1 = 1$ MHz. P1 must be set higher than the opamp's internal 50 kHz crossover frequency.

2) Calculate a second value for C2 using the following formula:

 $C2 \geq (R1 \cdot C_{in}) / R2$, where Cin = 50 pF

3) Use the larger of the two values calculated in steps 1 & 2.

Verify the Opamp Compensation:

Verify the opamp compensation using the openloop gain and phase response Bode plot in [Figure 15.](#page-7-2) Plot the calculated closed loop gain transfer function and verify the following design criteria are met:

- Pole P1 > opamp internal 50 kHz crossover frequency
	- $-$ P1 = 1 / [2 π (R1||R2) \bullet C2], where P1 = 1 MHz
	- To simplify the calculation, set the pole to $P1 = 1$ MHz.
- Z1 < opamp internal 50 kHz crossover frequency
	- $-Z1 = 1/(2π R2 C2)$
- Gain margin above the open-loop gain transfer function is required. A gain margin of +20 dB above the open loop gain transfer function is optimal.

3.3 Powerdown (PDWN)

The CS3001 single amplifier provides a powerdown function on pin 1. If this pin is left open the amplifier will operate normally. If the powerdown is asserted low, the amplifier will go into a low power state. There is a pull-up resistor (approximately 800 kΩ) inside the amplifier from pin 1 to the V+ supply. The current through this pull-up resistor is the main source of current drain in the powerdown state.

3.4 Applications

The CS3001 and CS3002 amplifiers are optimum for applications that require high gain and low drift. [Figure 19](#page-12-1) illustrates a thermopile amplifier with a gain of 650 V/V. The thermopile outputs only a few millivolts when subjected to infrared radiation. The amplifier is compensated and bandlimited by C1 in combination with R2.

[Figure 20, on page 15](#page-12-2) illustrates a load cell bridge amplifier with a gain of 768 V/V. The load cell is excited with $+5$ V and has a 1 mV/V sensitivity. Its full scale output signal is amplified to produce a fully differential \pm 3.8 V into the CS5510/12 A/D converter. This circuit operates from +5 V.

A similar circuit operating from +3 V can be constructed using the CS5540/CS5541 A/D converters.

Therm opne Am pimer with a Gam or 650 V/V **Figure 19. Thermopile Amplifier with a Gain of 650 V/V**

Figure 20. Load Cell Bridge Amplifier and A/D Converter

CS3001 CS3002

4. PACKAGE DRAWING

8L SOIC (150 MIL BODY) PACKAGE DRAWING

JEDEC #: MS-012

5. ORDERING INFORMATION

6. ENVIRONMENTAL, MANUFACTURING, & HANDLING INFORMATION

* MSL (Moisture Sensitivity Level) as specified by IPC/JEDEC J-STD-020.

7. REVISION HISTORY

Contacting Cirrus Logic Support

For all product questions and inquiries contact a Cirrus Logic Sales Representative. To find the one nearest to you go to www.cirrus.com

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